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# WSP6582C

*SwitchPro* Family High Fidelity Stereo SPDT Switch with Pop and Click Suppression

### Descriptions

With *SwitchPro* technology, The WSP6582C is a Dual SPDT analog switch with ultra-low distortion, high OFF-Isolation for special stereo audio applications with negative swing audio signals capacity that features ultra-low Ron of  $0.2\Omega$  (typical) at 3.3V VCC.

The WSP6582C operates a single power supply over a wide range from 3.0V to 4.5V and 1.8V logic compatible with ultra high PSRR. With soft-start feature that eliminates pops and clicks associated at any application conditions likes switched, enable/disable and power-up.

With superior THD+N performance and other high performance, the WSP6582C is an ideal device for Hi-Fi system applications.

The WSP6582C is available in 12 Ball Wafer Level Chip Scale Package (WLCSP) with 1.2x1.6x0.5mm. All products is Pb-free and Halogen-free.

### Features

- Single supply range operating from 3.0V to 4.5V
- -118dB THD+N into 100kΩ load at 2Vrms
- -114dB THD+N into 32Ω load at 2Vrms
- Signal-to-Noise (SNR) Ratio 132dBA
- 100dB PSRR at 10kHz
- 137dB crosstalk & separation
- Adjust soft-start with external capacitor

### Applications

- Hi-Fi Smartphones and Portable Device
- Hi-Fi SACD/DVD players
- High Quality Home Theaters

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WLCSP-12B (Bottom view)



Pin configuration (Top view)



W = Week Code

## **Order information**

Device	Package	Shipping
WSP6582C-12/TR	WLCSP-12B	3000/Reel&Tape



# **Pin descriptions**

Pin Number	Symbol	Descriptions		
A1	L1	Left normally closed pin		
A2	L	Left common pin		
A3	L2	Left normally open pin		
B1	VCC	Power supply		
B2	SEL1	Select control pin for Left		
B3	CAP	Soft-start rising time control with external ceramic capacitor		
C1	MUTE	Signal mute control pin		
C2	SEL2	Select control pin for Right		
C3	GND	Ground		
D1	R1	Right normally closed pin		
D2	R	Right common pin		
D3	R2	Right normally open pin		

# **Block Diagram**





# **Function Table**

MUTE	SEL1	SEL2	L1	L2	R1	R2
0	0	0	ON	OFF	ON	OFF
0	0	1	ON	OFF	OFF	ON
0	1	0	OFF	ON	ON	OFF
0	1	1	OFF	ON	OFF	ON
1	Х	Х	OFF	OFF	OFF	OFF

#### Note: X=0 or 1, don't care

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# **Typical Applications**



Figure 2. Hi-Fi Phone Application Block Diagram



# Absolute Maximum Ratings (1)

Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	-0.3 ~ 5.5	V
Digital Control Input Voltage	V <sub>IN</sub>	-0.3 ~ 5.5	V
Analog Input/Output Voltage (L1,L2,R1,R2,L,R)	Vis	-4.0 ~ 4.0	V
Switch Continuous Current (L1,L2,R1,R2,L,R)	lio	±300	mA
Switch Peak Current (L1,L2,R1,R2,L,R) (pulsed at 1ms, 10% duty cycle, Max)	Ію_рк	±500	mA
Power Dissipation in Still Air	PD	250	mW
Storage Temperature Range	T <sub>STG</sub>	-55 ~ 150	°C
Junction Temperature	TJ	150	°C
Lead Temperature (Soldering, 10 seconds)	TL	260	°C
Thermal Resistance	R <sub>0JA</sub>	80	°C/W
ESD protection (HDM)	I/O to VCC, I/O to GND	±6000	V
ESD protection (HBM)	I/O to I/O	±4000	V

# Recommend operating ratings <sup>(2)</sup>

Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	3.3 ~ 4.5	V
Digital Control Input Voltage	V <sub>IN</sub>	0.0 ~ V <sub>CC</sub>	V
Analog Input/Output Voltage (L1,L2,R1,R2,L,R)	V <sub>IS</sub>	-3.3 ~ V <sub>CC</sub>	V
Operating Temperature	T <sub>A</sub>	-40 ~ 85	О°

#### Note:

- 1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- 2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.



### **DC Electronics Characteristics**

(Ta=25°C, VCC=3.6V, V<sub>IS</sub>=2Vrms, R<sub>L</sub>=32Ω, f=1kHz, CAP=0.1uF, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Analog Switch Characteristics			•	•		
Analog Signal Range	Vis	VCC: 3.3 ~ 4.2		2.5		Vrms
		V <sub>IS</sub> = -3.3V~+3.3V				0
On-Resistance	Ron	I <sub>OUT</sub> =100mA		0.2		Ω
Ron Matching		V <sub>IS</sub> = -3.3V~+3.3V		0.0015		0
Between Channels	$\Delta R_{ON}$	Ι <sub>ουτ</sub> =100mΑ		0.0015		Ω
Ron Flatness	D-1	V <sub>IS</sub> = -3.3V~+3.3V		0.0045		Ω
RON FIGURESS	RFLAT(ON)	Iout=100mA		0.0015		12
Dynamic Characteristics						
Total Harmonic Distortion	THD+N	f=10Hz to 22KHz		-118		dB
		Vıs=2Vrms @R∟=100kΩ		-110		UD
Total Harmonic Distortion	THD+N	f=10Hz to 22KHz		-114		dB
		Vıs=2Vrms @R∟=32Ω		-114		UD
		f=10Hz to 500kHz				
Total Harmonic Distortion	THD+N	V <sub>IS</sub> =1.55Vrms		-104		dB
		@RL=100kΩ				
		Mode=CCIF 19k+20k		-122		
Intermodulation Distortion	IMD	Ratio=1				dB
		Vis=500mVrms				4.0
		@R∟=100kΩ				
Dynamic/Transient		Mode=DIM100				
Intermodulation Distortion	IMD	VIS=1Vrms		-103		dB
		@ RL=100kΩ				
		f=10Hz to 22KHz,		132		dBA
Signal-to-Noise Ratio	SNR	Inputs grounded				
		$R_L=32\Omega$ or $100k\Omega$				
Stereo Channel Imbalance	IMB	f=10Hz to 22KHz,		±0.003		dB
L1 and R1, L2 and R2		R∟=100kΩ				-
		f=10Hz to 22KHz,		127		
Off isolation (Muting)	OIRR	$V_L = V_R = 2Vrms$				dB
		@R∟=32Ω				
		MUTE=VCC SEL="X"				
		f=10Hz to 22KHz,				
Crosstalk (Channel-to-Channel)	Xtalk	V <sub>IS</sub> = 2Vrms,		137		dB
		Source Impedance=0Ω				-
		R <sub>L</sub> = 100kΩ				
		f=10kHz,		100		
Power Supply Ripple Rejection	PSRR	$V_{IS} = 0.1 V rms,$				dB
		Inputs grounded				
-3dB Bandwidth	BW	R∟=50Ω		50		MHz
On-to-Mute Time	T <sub>TRS-OM</sub>	CAP=0.1uF		50		ns

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Mute-to-On Time	T <sub>TRS-MO</sub>	CAP=0.1uF		160		ms
Turn-Off Time	TOFF	V <sub>IS</sub> =1.5V, R∟=20KΩ	60		n	ns
	1011	MUTE=0			'	110
Turn-On Time	Ton	$V_{IS}$ =1.5V, RL=20K $\Omega$		60		us
	TON	MUTE=0				40
Break-Before-Make time	Тввм	$V_{IS}$ =1.5V, RL=20K $\Omega$		50		us
Dieak-Deloie-Make linie	IBBM	MUTE=0		50		
Lx, Rx Off capacitance	COFF	f=100kHz,		15		pF
	COFF	$V_{Lx}$ or $V_{Rx}$ = $V_L$ or $V_R$ =0V		15		μr
L, R On capacitance	Con	f=100kHz,		30		pF
L, R On capacitance	CON	$V_{Lx}$ or $V_{Rx}$ = $V_L$ or $V_R$ =0V				рг
Power Supply Characteristics						
Supply guidecont ourrent	lcc	MUTE=0V		190		uA
Supply quiescent current	ICC	MUTE=VCC		55		uA
Digital Input Characteristics						
Digital input logic high level	V	VCC=3.6~4.5	1.6			V
	VIH	VCC=3.0~3.6	1.5			V
Disitel input lesis leveloyel	V	VCC=3.6~4.5			0.5	V
Digital input logic low level	VIL	VCC=3.0~3.6			0.4	V
Digital Input leakage current	lin				±2.0	uA
SEL pull-down resistor	R <sub>PD</sub>			4		MΩ
MUTE pull-up resistor	Rpu			4		MΩ

Note:

3. Flatness is defined as the difference between maximum and minimum value of ON-resistance at the specified analog signal voltage points.

4. R<sub>ON</sub> matching between channels is calculated by subtracting the channel with the highest max Ron value from the channel with lowest max ron value.

5. Crosstalk is inversely proportional to source impedance.

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WSP6582C

**Test Circuits** 





**ON-Resistance** (R<sub>ON</sub>)







Crosstalk (Xtalk)

Off isolation (OIRR)



Bandwidth (BW)



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# Package outline dimensions

WLCSP-12B





Side View

Cymhol	I	Dimensions in millimete	ər
Symbol	Min.	Тур.	Max.
Х	1.180	1.205	1.230
Y	1.610	1.635	1.660
X1		0.077	
X2		0.400	
X3	0.230	0.250	0.270
Y1		0.400	
Y2		0.077	
Z	0.480	0.535	0.590
Z1	0.305	0.330	0.355
Z2	0.145	0.165	0.185